

BD442

PNP power transistor

Features

PNP transistor

Applications

■ Linear and switching industrial equipment

Description

This devices is manufactured in Planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The NPN type is BD441.

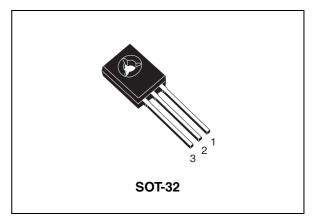


Figure 1. Internal schematic diagram

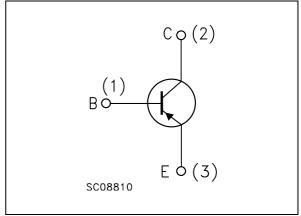


Table 1. Device summary

Order code	Marking	Package	Packaging
BD442	BD442	SOT-32	Tube

June 2	800
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Absolute maximum ratings 1

Table 2.	Absolute	maximum	rati
	Absolute	maximam	Iuu

Table 2. Absolute maximum ratings			
Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage $(I_E = 0)$	-80	V
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	-80	V
V _{CEO}	Collector-emitter voltage $(I_B = 0)$	-80	V
V _{EBO}	Emitter-base voltage ($I_{C} = 0$)	-5	V
۱ _C	Collector current	-4	A
I _{CM}	Collector peak current (t _p < 10 ms)	-7	A
Ι _Β	Base current	-1	A
P _{TOT}	Total dissipation at T _{case} = 25 °C	36	W
T _{stg}	Storage temperature	-65 to 150	°C
Т _Ј	Max. operating junction temperature	150	°C

57

BD442

2 Electrical characteristics

($T_{case} = 25 \ ^{\circ}C$; unless otherwise specified)

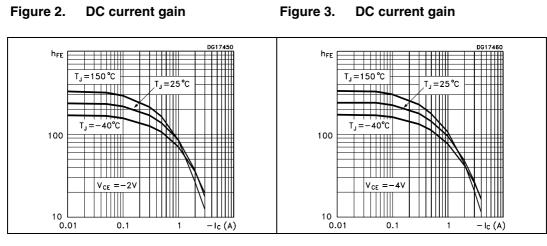
Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current $(I_E = 0)$	V _{CB} = -80 V				-0.1	mA
I _{CES}	Collector cut-off current $(V_{BE} = 0)$	V _{CE} = -80 V				-0.1	mA
I _{EBO}	Emitter cut-off current $(I_{C} = 0)$	V _{EB} = -5 V				-1	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = -100 mA		-80			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = -2 A	I _B = -0.2 A			-0.8	V
V _{BE} ⁽¹⁾	Base-emitter voltage	I _C = -10 mA I _C = -2 A	V _{CE} = -5 V V _{CE} = -1 V		-0.58	-1.5	V V
h _{FE} ⁽¹⁾	DC current gain	$I_{C} = -10 \text{ mA}$ $I_{C} = -500 \text{ mA}$ $I_{C} = -2 \text{ A}$	02	15 40 15	130 140		

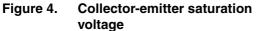
Table 3. Electrical characteristics

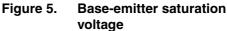
1. Pulsed duration = 300 ms, duty cycle \geq 1.5%.



Electrical characteristics (curves) 2.1







– V_{BE(sat)} (V)

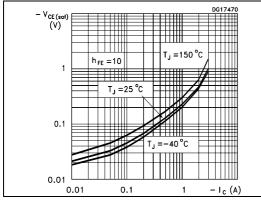
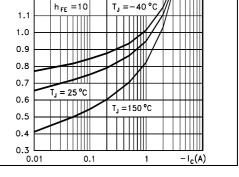


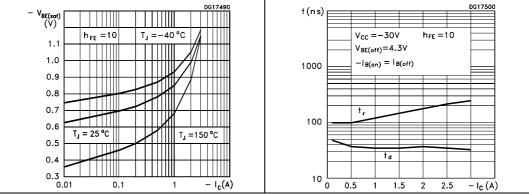
Figure 6. Collector-emitter on voltage



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57





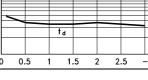
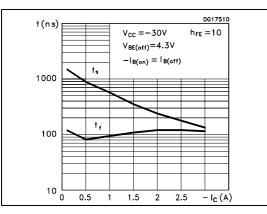
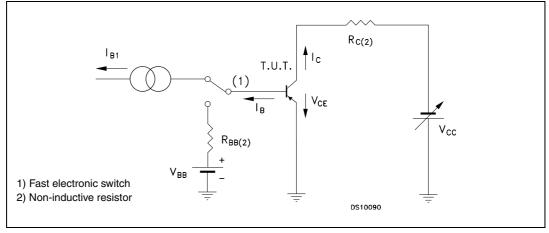


Figure 8. Resistive load switching time



2.2 Test circuit

Figure 9. Resistive load switching test circuit



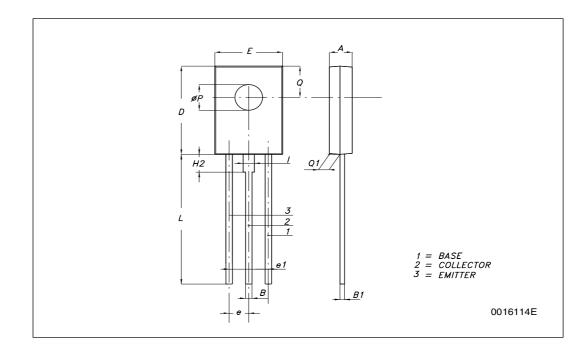


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



	SOT-32 (TO-126) mechanical data			
DIM.	mm.			
	MIN.	ТҮР	MAX.	
A	2.4		2.9	
В	0.64		0.88	
B1	0.39		0.63	
D	10.5		11.05	
E	7.4		7.8	
е	2.04	2.29	2.54	
e1	4.07	4.58	5.08	
L	15.3		16	
Р	2.9		3.2	
Q		3.8		
Q1	1		1.52	
H2		2.15		
I		1.27		





4 Revision history

Table 4.Document revision history

Date	Revision	Changes
08-Feb-2008	1	Initial Release
09-Jun-2008	2	Removed BD440



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